





SN74AC573

SCAS542G - OCTOBER 1995 - REVISED NOVEMBER 2023

SN74AC573 Octal D-type Transparent Latches with 3-State Outputs

1 Features

- Operation of 2 V to 6 V V _{CC}
- Inputs accept voltages to 6 V
- Maximum t_{pd} of 9 ns at 5 V
- 3-State outputs drive bus lines directly

2 Applications

- **Buffer registers**
- Bidirectional bus drivers
- Working registers

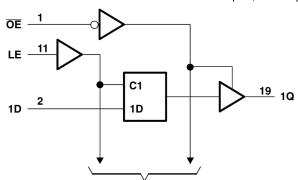
3 Description

These 8-bit latches feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. The devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

Package Information								
PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾						
	RKS (VQFN, 20)	4.5 mm × 2.5 mm						
	DB (SSOP, 20)	7.2 mm × 7.8 mm						
	DGV (TVSOP, 20)	5 mm × 6.4 mm						
SN74AC573	DW (SOIC, 20)	12.8 mm × 10.3 mm						
	NS (SOP, 20)	12.6 mm × 7.8 mm						
	N (PDIP, 20)	24.33 mm × 9.4 mm						
	PW (TSSOP, 20)	6.5 mm × 6.4 mm						

For more information, see Section 10. (1)

(2)The package size (length × width) is a nominal value and includes pins, where applicable.



To Seven Other Channels Logic Diagram (Positive Logic)





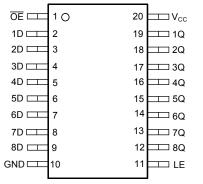
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4 Pin Configuration and Functions



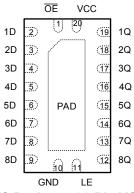


Figure 4-1. DB, DGV, DW, NS, N, or PW Packages, 20-Pin SSOP, TVSOP, SOIC, SOP, PDIP, or TSSOP (Top View)



	PIN		DESCRIPTION
NAME	NO.		DESCRIPTION
OE	1	I	Output enable
1D	2	I	1D input
2D	3	I	2D input
3D	4	1	3D input
4D	5	1	4D input
5D	6	I	5D input
6D	7	I	6D input
7D	8	I	7D input
8D	9	1	8D input
GND	10	_	Ground
LE	11	1	Latch enable input
8Q	12	0	8Q output
7Q	13	0	7Q output
6Q	14	0	6Q output
5Q	15	0	5Q output
4Q	16	0	4Q output
3Q	17	0	3Q output
2Q	18	0	2Q output
1Q	19	0	1Q output
V _{CC}	20	_	Power pin
Thermal	Pad ⁽²⁾	_	The thermal pad can be connect to GND or left floating. Do not connect to any other signal or supply.

Table 4-1. Pin Functions

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.

(2) For RKS package only.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	+ 7	V
V _I ²	Input voltage range		-0.5	V _{CC} + 0.5	V
V_0^2	Output voltage range		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	$(V_{I} < 0 \text{ or } V_{I} > V_{CC})$		±20	mA
I _{OK}	Output clamp current	$(V_O < 0 \text{ or } V_O > V_{CC})$		±20	mA
I _O	Continuous output current	$(V_{O} = 0 \text{ to } V_{CC})$		±50	mA
	Continuous current through, V_{CC} or GN	ID		±200	mA
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)¹

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2	6	V
		V _{CC} = 3 V	2.1		
V _{IH}	High-level input voltage	V _{CC} = 4.5 V	3.15		V
		V _{CC} = 5.5 V	3.85		
		V _{CC} = 3 V		0.9	
V _{IL}		V _{CC} = 4.5 V		1.35	V
		V _{CC} = 5.5 V		1.65	
VI	Input voltage	· · · ·	0	V _{CC}	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 3 V		-12	
I _{OH}	High-level output current	V _{CC} = 4.5 V		-24	mA
		V _{CC} = 5.5 V		-24	
		V _{CC} = 3 V		12	
I _{OL}	Low-level output current	V _{CC} = 4.5 V		24	mA
		V _{CC} = 5.5 V		24	
Δt/Δv	Input transition rise or fall rate			8	ns/V
T _A	Operating free-air temperature		-40	85	°C

All unused inputs of the device must be held at V_{CC} or GND for proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



5.3 Thermal Information

	THERMAL METRIC	DW (SOIC)	DW (SOIC) DB (SSOP)		NS (SO)	PW (TSSOP)	RKS (VQFN)	UNIT
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
R _{θJA}	Junction-to-ambient thermal resistance ⁽¹⁾	58	70	69	60	83	68	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST CONDITIONS	V	Τ ₄	_Δ = 25°C		SN74AC	573	UNIT
PARAMETER	TEST CONDITIONS	V _{cc}	MIN	ТҮР	MAX	MIN	MAX	UNIT
		3 V	2.9			2.9		
	I _{OH} = −50 μA	4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		
V _{OH}	I _{OH} = −12 mA	3 V	2.58			2.48		V
	L = 24 mA	4.5 V	3.94			3.8		
	$I_{OH} = -24 \text{ mA}$	5.5 V 4.94	4.94			4.8		
	I _{OH} = -75 mA ⁽¹⁾	5.5 V				3.85	3.85 0.1	
		3 V			0.1		0.1	
	I _{OL} = 50 μA	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
V _{OL}	I _{OL} = 12 mA	3 V			0.36		0.44	V
	L = 24 mA	4.5 V			0.36		2.9 4.4 5.4 2.48 3.8 4.8 3.85 0.1 0.1 0.1 0.1	
	I _{OL} = 24 mA	5.5 V			0.36		0.44	
	I _{OL} = 75 mA	5.5 V					1.65	
l _l	V _I = V _{CC} or GND	5.5 V			±0.1		±1	μA
I _{OZ}	V _O = V _{CC} or GND	5.5 V			±0.25		±2.5	μA
I _{CC}	$V_{I} = V_{CC} \text{ or GND}, \qquad I_{O} = 0$	5.5 V			4		40	μA
C _i	V _I = V _{CC} or GND	5 V		5				pF

(1) Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

5.5 Timing Requirements, V_{CC} = 3.3 V ± 0.3 V

over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C	T _A = 25°C		SN74AC573		
		MIN	MAX	MIN	MAX	UNIT	
tw	Pulse duration, LE high	6		7		ns	
t _{su}	Setup time, data before LE↓	3.5		4		ns	
t _h	Hold time, data after LE↓	2		2		ns	

5.6 Timing Requirements, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T _A = 25°C		SN74AC	573	UNIT
		MIN	MAX	MIN	MAX	UNIT
t _w	Pulse duration, LE high	4		5		ns
t _{su}	Setup time, data before LE \downarrow	3		3.5		ns
t _h	Hold time, data after LE↓	2		2		ns

5.7 Switching Characteristics, V_{CC} = 3 V ± 0.3 V

over recommended operating free-air temperature range, V_{CC} = 3 V ± 0.3 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T _A = 2	5°C	SN74AC	573	UNIT
		10 (001701)	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	D	Q	2.5	13	2	15	ns
t _{PHL}		Q	2.5	12	2	14	115
t _{PLH}		Q	2.5	13	2	15	50
t _{PHL}	LE	Q	2.5	12	2	14	ns
t _{PZH}	ŌĒ	Q	2.5	11	2	12	ne
t _{PZL}	OE	Q	2.5	11	2	12.5	ns
t _{PHZ}	ŌĒ	Q	2.5	12.5	2	13.5	ns
t _{PLZ}	UL	Q	2.5	9.5	2	10.5	115

5.8 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range, $V_{CC} = 5 V \pm 0.5 V$ (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER		FROM (INPUT) TO (OUTPUT)	T _A = 25°C		SN74AC573		UNIT
FARAMETER	FROM (INPUT)	10 (001901)	MIN	MAX	MIN	MAX	UNIT
t _{PLH}	D	Q	2.5	10	2	11.5	n 0
t _{PHL}	D	Q	2.5	9.5	2	11	ns
t _{PLH}	15	Q	2.5	9.5	2	11	n 0
t _{PHL}	LE	Q	2.5	8.5	2	10	ns
t _{PZH}		Q	2.5	9	2	10	n 0
t _{PZL}	ŌĒ	Q Q	2.5	8.5	2	9.5	ns
t _{PHZ}		0	2.5	11	2	12	n 0
t _{PLZ}		OE Q	2.5	8	2	9	ns

5.9 Operating Characteristics

 V_{CC} = 5 V, T_{A} = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	25	pF



Vcc

0 V

٧_{cc}

0 V

 v_{cc}

0 V

≈Vcc

VOL

VOH

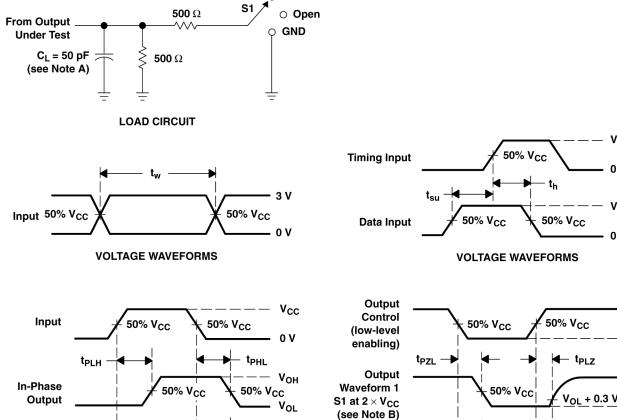
≈0 V

- t_{PHZ}

50% V_{CC}

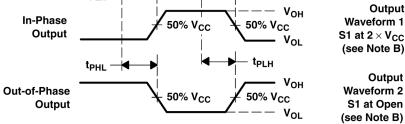
VOLTAGE WAVEFORMS

V_{OH} – 0.3 V



 $2 \times V_{CC}$

6 Parameter Measurement Information



VOLTAGE WAVEFORMS

- C_L includes probe and jig capacitance. Α.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 Β. is for an output with internal conditions such that the output is high except when disabled by the output control.

t_{PZH} –

Output

- All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns. C.
- D The outputs are measured one at a time with one input transition per measurement.

Figure 6-1. Load Circuit a	nd Voltage Waveforms
----------------------------	----------------------

Table 6-1.						
TEST	S1					
t _{PLH} /t _{PHL}	Open					
t _{PLZ} /t _{PZL}	2 × V _{CC}					
t _{PHZ} /t _{PZH}	Open					



7 Detailed Description

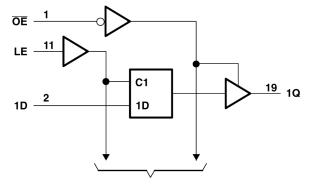
7.1 Overview

The eight latches are D-type transparent latches. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D Inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines in a bus-organized system without need for interface or pullup components.

 \overline{OE} does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

7.2 Functional Block Diagram



To Seven Other Channels

Figure 7-1. Logic Diagram (Positive Logic)

7.3 Device Functional Modes

Table 7-1. Function Table (Each Latch)									
I	NPUTS ⁽¹⁾	OUTPUT ⁽²⁾ Q							
OE	LE	D							
L	Н	н	Н						
L	Н	L	L						
L	L	Х	Q ₀						
Н	Х	Х	Z						

(1) H = High voltage level, L = Low voltage level, X = High or low voltage level

(2) H = Driving high, L = Driving low, Q_0 = Driving previous high or low state, Z = High impedance



8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.3 Trademarks

TI E2E[™] is a trademark of Texas Instruments. All trademarks are the property of their respective owners.

8.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision F (June 2023) to Revision G (November 2023)	Page
 Updated the <i>Package Information</i> table to include package lead size Added the <i>RKS</i> package information 	
Changes from Revision E (May 2023) to Revision F (June 2023)	Page

•	Updated high-level input voltage values in <i>Recommended Operating Conditions</i> table4
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Changes from Revision D (October 2003) to Revision E (May 2023)

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Page



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AC573DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573DBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 85	AC573	
SN74AC573DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples
SN74AC573DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573N	ACTIVE	PDIP	Ν	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74AC573N	Samples
SN74AC573NS	LIFEBUY	SO	NS	20	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	
SN74AC573NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 85	AC573	
SN74AC573PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples
SN74AC573PWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	AC573	Samples
SN74AC573RKSR	ACTIVE	VQFN	RKS	20	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AC573	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



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PACKAGE OPTION ADDENDUM

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74AC573 :

• Automotive : SN74AC573-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



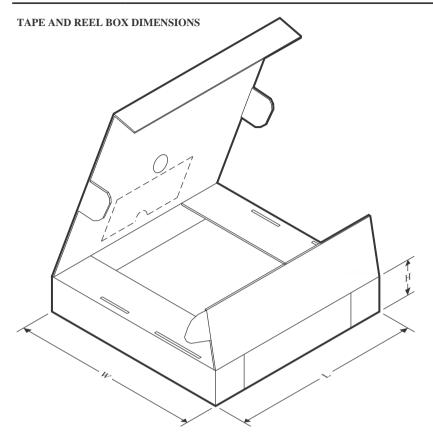
*All dimensions are nominal												t.
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AC573DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AC573DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AC573NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AC573PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AC573RKSR	VQFN	RKS	20	3000	180.0	12.4	2.8	4.8	1.2	4.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

18-Dec-2023



*All	dimensions	are	nominal	
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AC573DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AC573DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AC573NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AC573PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AC573RKSR	VQFN	RKS	20	3000	210.0	185.0	35.0

TEXAS INSTRUMENTS

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18-Dec-2023

TUBE



- B - Alignment groove width

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74AC573N	N	PDIP	20	20	506	13.97	11230	4.32
SN74AC573NS	NS	SOP	20	40	530	10.5	4000	4.1

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW0020A



PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



DW0020A

EXAMPLE BOARD LAYOUT

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DW0020A

EXAMPLE STENCIL DESIGN

SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW0020A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0020A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0020A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB0020A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



DB0020A

EXAMPLE BOARD LAYOUT

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DB0020A

EXAMPLE STENCIL DESIGN

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



RKS 20

2.5 x 4.5, 0.5 mm pitch

GENERIC PACKAGE VIEW

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





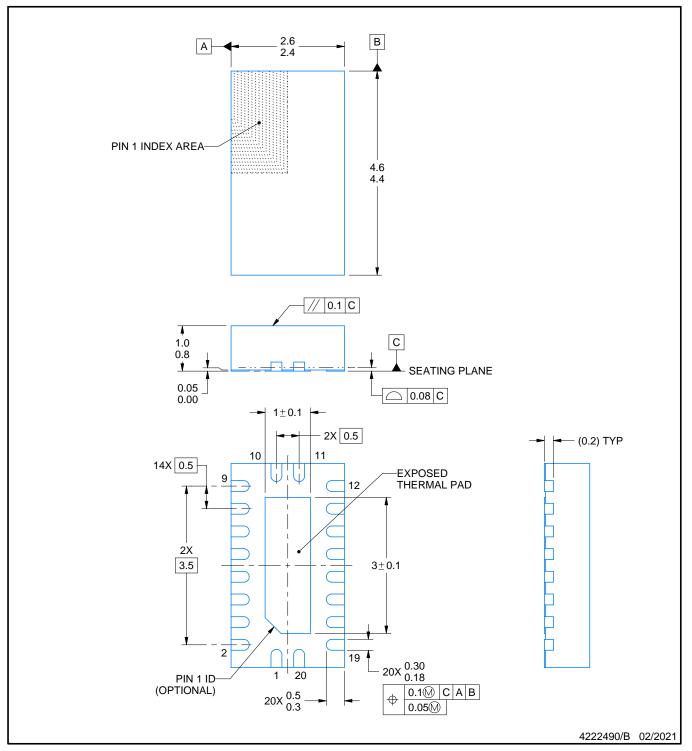
RKS0020A



PACKAGE OUTLINE

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

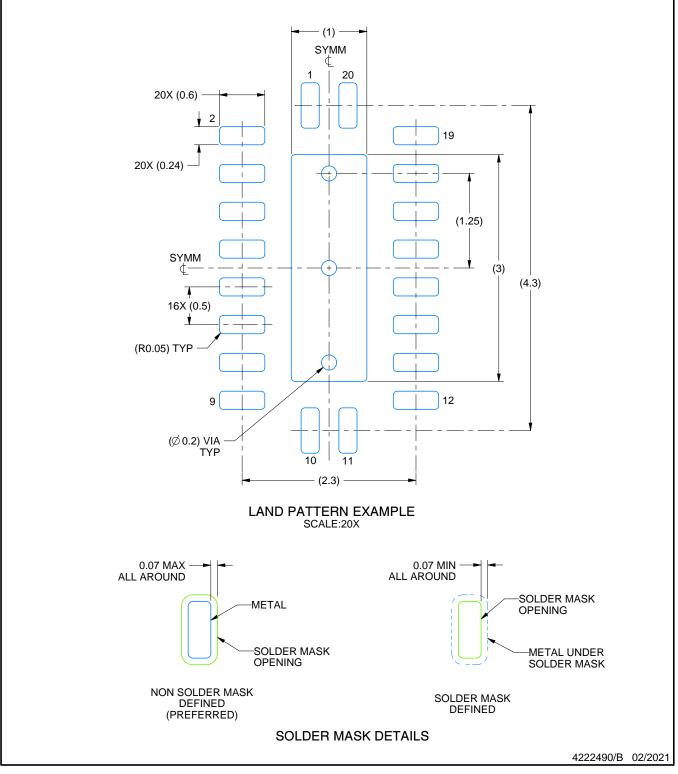


RKS0020A

EXAMPLE BOARD LAYOUT

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

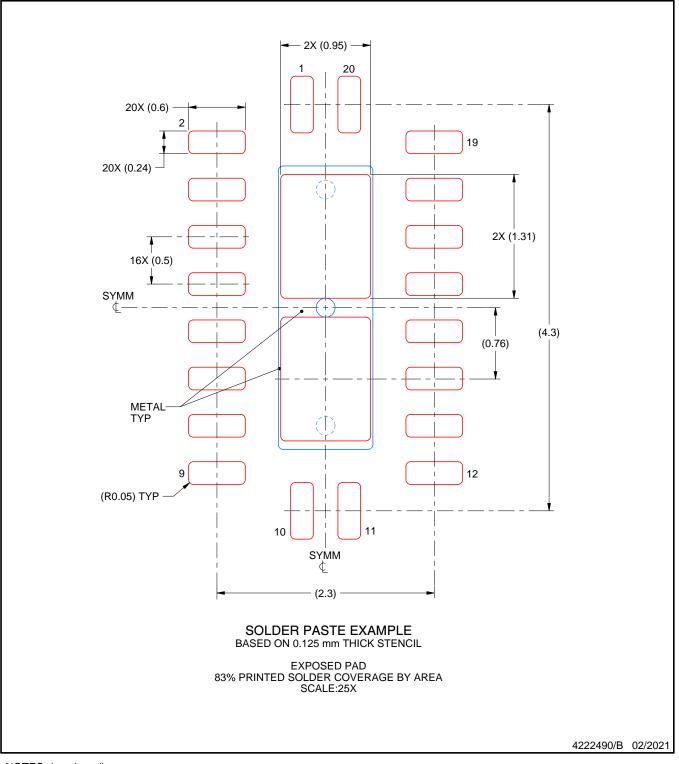


RKS0020A

EXAMPLE STENCIL DESIGN

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



MECHANICAL DATA

PLASTIC SMALL-OUTLINE PACKAGE

0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 \bigcirc Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS ** 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G**)

14-PINS SHOWN

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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